



0.5 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

Typical Applications

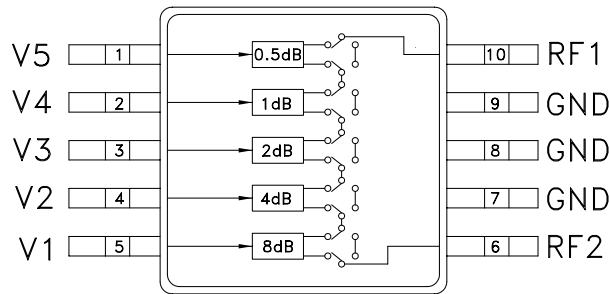
The HMC306AMS10 / 306AMS10E is ideal for:

- Cellular; UMTS/3G Infrastructure
- ISM, MMDS, WLAN, WiMAX
- Microwave Radio & VSAT
- Test Equipment and Sensors

Features

- RoHS-Compliant Product
- 0.5 dB LSB Steps to 15.5 dB
- Single Positive Control Per Bit
- ± 0.2 dB Typical Bit Error
- Miniature 15 mm² Package: MSOP10

Functional Diagram



General Description

The HMC306AMS10 & HMC306AMS10E are general purpose broadband 5-bit positive control GaAs IC digital attenuators in 10 lead MSOP surface mount plastic packages. Covering 0.7 to 3.8 GHz, the insertion loss is typically less than 1.5 to 2.3 dB. These attenuators' bit values are 0.5 (LSB), 1, 2, 4 and 8 dB for a total attenuation of 15.5 dB. Attenuation accuracy is excellent at ± 0.2 dB typical with an IIP3 of up to +52 dBm. Five bit control voltage inputs, toggled between 0 and +3 to +5V, are used to select each attenuation state. A single Vdd bias of +3 to +5V applied through an external 5K Ohm resistor is required.

Electrical Specifications,

$T_A = +25^\circ C$, $V_{dd} = +3V$ to $+5V$ & $V_{CTL} = 0/V_{dd}$ (Unless Otherwise Stated)

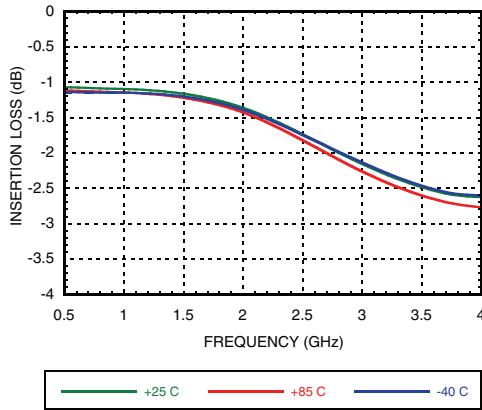
Parameter	Frequency (GHz)	Min.	Typical	Max.	Units
Insertion Loss	0.7 - 1.4		1.3	1.6	dB
	1.4 - 2.3		1.5	2.0	dB
	2.3 - 2.7		1.8	2.5	dB
	2.7 - 3.8		2.3	2.7	dB
Attenuation Range			15.5		dB
Return Loss (RF1 & RF2, All Atten. States)	0.7 - 1.4	15	21		dB
	1.4 - 2.3	14	18		dB
	2.3 - 2.7	13	16		dB
	2.7 - 3.8	10	13		dB
Attenuation Accuracy: (Referenced to Insertion Loss) All Attenuation States 0.5 - 7.5 dB States 8.0 - 15.5 dB States All Attenuation States	0.7 - 1.4	± (0.30 + 5% of Atten. Setting) Max.			dB
	1.4 - 2.3	± (0.25 + 3% of Atten. Setting) Max.			dB
	1.4 - 2.3	± (0.15 + 3% of Atten. Setting) Max.			dB
	2.3 - 3.8	± (0.30 + 3% of Atten. Setting) Max.			dB
Input Power for 0.1 dB Compression	0.7 - 3.8	Vdd = 5V	28		dBm
		Vdd = 3V	27		dBm
Input Third Order Intercept Point (Two-tone Input Power = 10 dBm Each Tone)	0.7 - 3.8	Vdd = 5V	52		dBm
		Vdd = 3V	48		dBm
Switching Characteristics	0.7 - 3.8	tRISE, tFALL (10/90% RF)	560		ns
		tON, tOFF (50% CTL to 10/90% RF)	600		ns



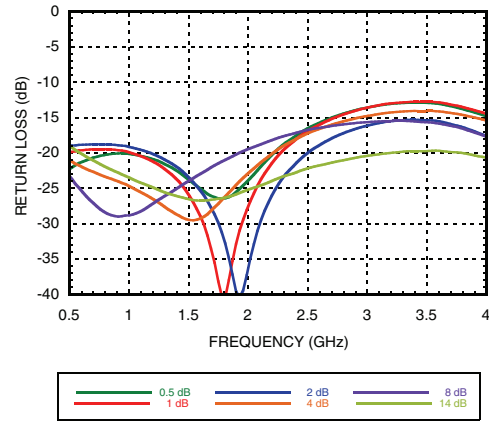
HMC306AMS10 / 306AMS10E

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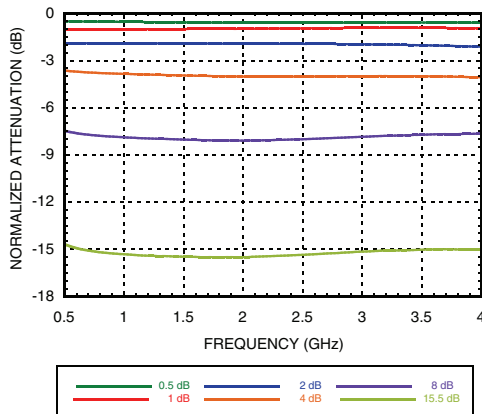
Insertion Loss



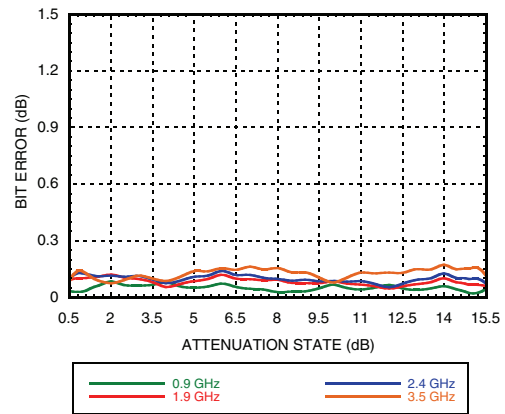
Return Loss RF1, RF2 (Only Major States are Shown)



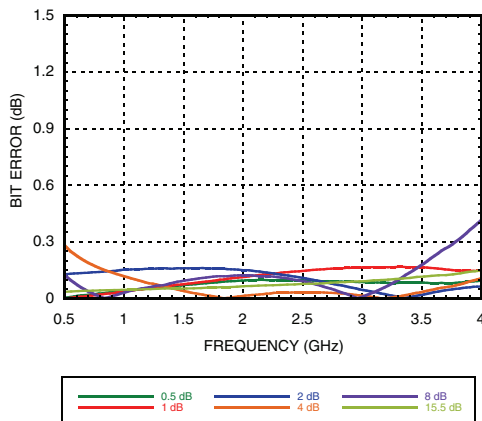
Normalized Attenuation (Only Major States are Shown)



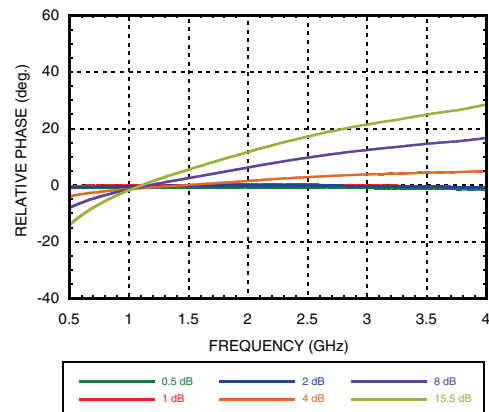
Absolute Bit Error vs. Attenuation State



Absolute Bit Error vs. Frequency (Only Major States are Shown)



Relative Phase vs. Frequency (Only Major States are Shown)



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Truth Table

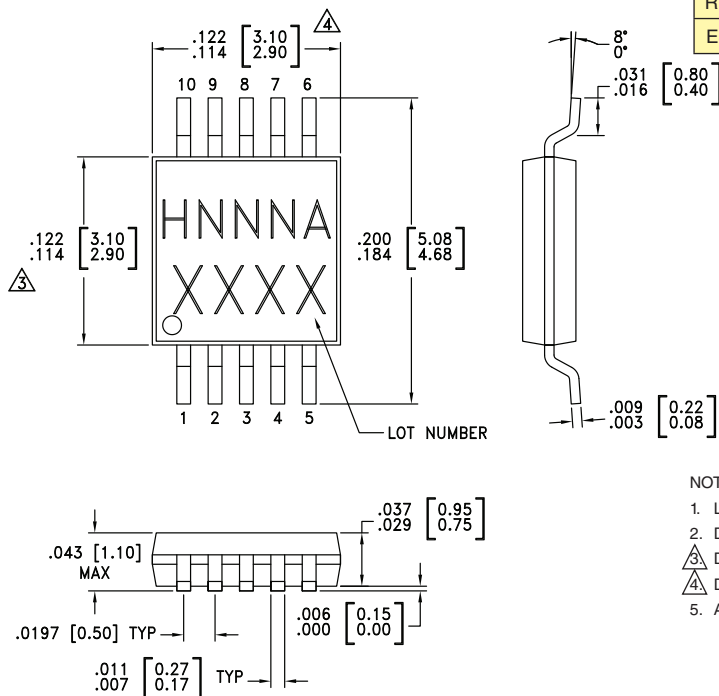
Control Voltage Input					Attenuation State RF1 - RF2
V1 8 dB	V2 4 dB	V3 2 dB	V4 1 dB	V5 0.5 dB	
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	0.5 dB
High	High	High	Low	High	1 dB
High	High	Low	High	High	2 dB
High	Low	High	High	High	4 dB
Low	High	High	High	High	8 dB
Low	Low	Low	Low	Low	15.5 dB Max. Atten.

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Control & Bias Voltages

State	Bias Condition
Low	0 to +0.2V @ 20 μ A Max.
High	Vdd \pm 0.2V @ 20 μ A Max.

Note: Vdd = +3V to 5V \pm 0.2V

Absolute Maximum Ratings

Control Voltage (V1 - V5)	Vdd + 0.2 Vdc
Bias Voltage (Vdd)	+8 Vdc
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 7.8 mW/ °C above 85 °C)	0.506 W
Thermal Resistance (Channel to package bottom)	128.5 °C/w
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
RF Input Power (0.7 - 3.8 GHz)	+27 dBm
ESD Sensitivity (HBM)	Class 1A

NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- \triangle DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- \triangle DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC306AMS10	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H306A XXXX
HMC306AMS10E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H306A XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX